NSN 5961-01-095-1658

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-095-1658 **Inclosure Material:** Metal **Overall Length:** 0.040 inches **Overall Diameter:** 0.145 inches **Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 collector to base voltage, dc and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 49956-710902 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No